# 2SC1921

## Silicon NPN Triple Diffused

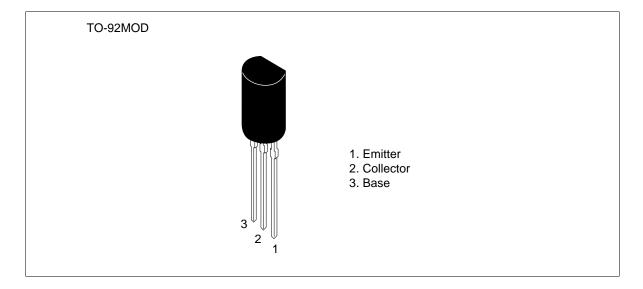
# **HITACHI**

ADE-208-1060 (Z) 1st. Edition Mar. 2001

### Application

- High frequency high voltage amplifier
- Video output

#### Outline





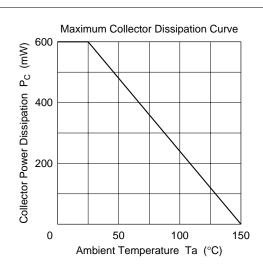
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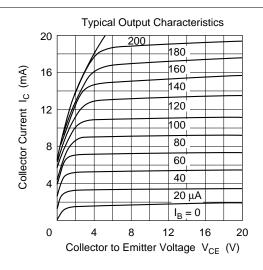
### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

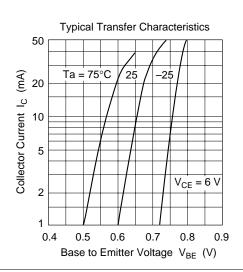
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	250	V
Collector to emitter voltage	V <sub>CEO</sub>	200	V
Emitter to base voltage	$V_{EBO}$	5	V
Collector current	Ic	50	mA
Collector power dissipation	P <sub>c</sub>	600	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

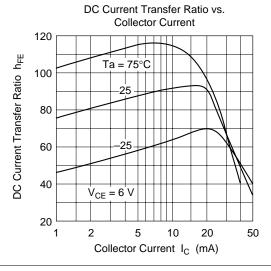
## Electrical Characteristics ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	250	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	200	_	_	V	$I_{C}$ = 1 mA, $R_{BE}$ = $\infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_{E} = 10 \ \mu A, \ I_{C} = 0$
Collector cutoff current	I <sub>CEO</sub>	_	_	1.0	μΑ	$V_{CE} = 120 \text{ V}, R_{BE} = \infty$
DC current transfer ratio	h <sub>FE</sub>	30	_	300		$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	_	1.0	V	$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 1 mA
Gain bandwidth product	f <sub>T</sub>	60	130	_	MHz	$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector output capacitance	Cob	_	3	4	pF	$V_{CB} = 6 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

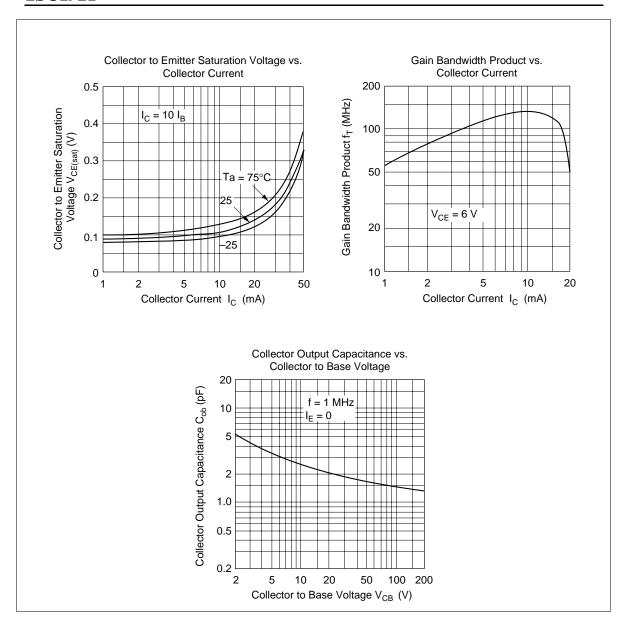




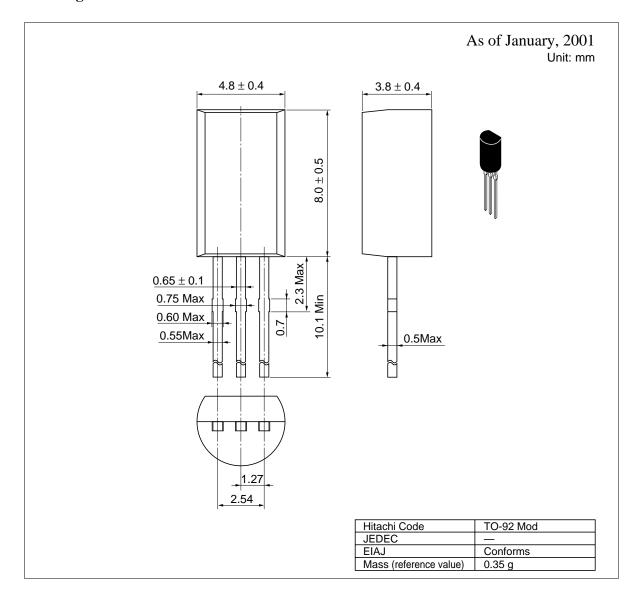




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#### **Package Dimensions**



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